MOS FET

SK8603170L

Panasonic

SK8603170L

Silicon N-channel MOS FET

For Load-switching / For DC-DC Converter

■ Features

- Low Drain-source On-state Resistance : RDS(on)typ = $3.9 \text{ m}\Omega$ (VGS = 4.5 V)
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL : Level 1 compliant)
- Marking Symbol : 17

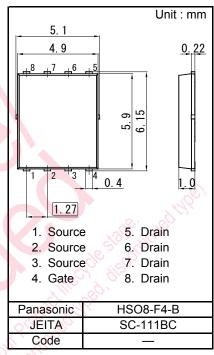
■ Packaging

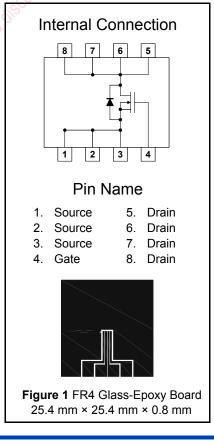
Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

■ Absolute Maximum Ratings Ta = 25 °C

Parameter			Symbol	Rating	Unit		
Drain to Source Voltage			VDS	30	V		
Gate to Source Voltage			VGS	±20	, A *(
	Ta = 25 °C, t = 10 s *1			28	"Online		
D	Ta = 25 °C, DC *1		ID	20			
Drain Current	Tc = 25 °C			59	OllA		
	Pulsed	I, Tch < 150 °C *2		84	blo		
Total Power			PD	2.8	w w		
Dissipation		Tc = 25 °C	PD	24			
Thermal Resistance		Channel to Ambient	Rth(ch-a)	44	°C / W		
		Channel to Case	Rth(ch-c)	5.1	-C / W		
Channel Temperature			Tch 🤇	150			
Operating ambient temperature			Topr	-40 to +85	°C		
Storage Temperature Range			Tstg	-55 to +150			
Avalanche Current (Single pulse) *3			IAR	14	Α		
Avalanche Energy (Single pulse) *3			EAR	24	mJ		

- Note *1 Device mounted on a glass-epoxy board in Figure 1
 - *2 Pulse test: Ensure that the channel temperature does not exceed 150 °C
 - *3 VDD = 24 V, VGS = 10 to 0 V, L = 0.1 mH, Tch = 25 °C (initial)





Established: 2012-12-20 Revised: 2013-05-31 Revision. 2

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■ Electrical Characteristics Ta = 25 °C ± 3 °C

Static Characteristics

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source Breakdown Voltage	VDSS	ID = 1 mA, VGS = 0 V	30			V
Zero Gate Voltage Drain Current	IDSS	VDS = 30 V, VGS = 0 V			10	μΑ
Gate-source Leakage Current	IGSS	VGS = ±16 V, VDS = 0 V			±10	μΑ
Gate-source Threshold Voltage	Vth	ID = 2.56 mA, VDS = 10 V	1.3		3	V
Drain-source On-state Resistance	RDS(on)1	ID = 14 A, VGS = 10 V		2.9	4.1	mΩ
Diain-source On-state Resistance	RDS(on)2	ID = 14 A, VGS = 4.5 V		3.9	5.8	

Dynamic Characteristics

Dynamic Onaracteristics						
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input Capacitance	Ciss	VDS = 10 V, VGS = 0 V		2 100	2 940	
Output Capacitance	Coss	f = 1 MHz		250	350	pF
Reverse Transfer Capacitance	Crss	- I = I IVIM2		180	290	
Turn-on Delay Time *1	td(on)	VDD = 15 V, VGS = 0 to 10 V		11	2. 0	
Rise Time *1	tr	ID = 14 A		10	Jun 1	ns
Turn-off Delay Time *1	td(off)	VDD = 15 V, VGS = 10 to 0 V		48	July 1	no
Fall Time *1	tf	ID = 14 A	1	7.5)	ns
Total Gate Charge	Qg	VDD = 45 V VCC = 0 to 4 5 V	ررهاي	17		
Gate to Source Charge	Qgs	VDD = 15 V, VGS = 0 to 4.5 V ID = 14 A	(11, ~	6		nC
Gate to Drain Charge	Qgd	ID - 14 A	Per 1	7		
Gate resistance	rg	f = 5 MHz	60	1.2	3	Ω

Body Diode Characteristic

Established: 2012-12-20

Revised

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Diode Forward Voltage	VSD	IS = 14 A, VGS = 0 V		0.8	1.2	V

Note: 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

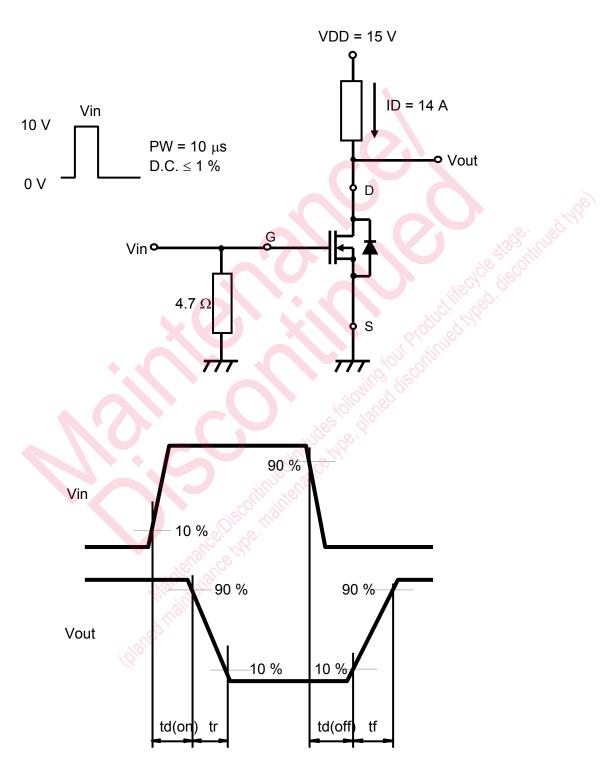
2. *1 Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time

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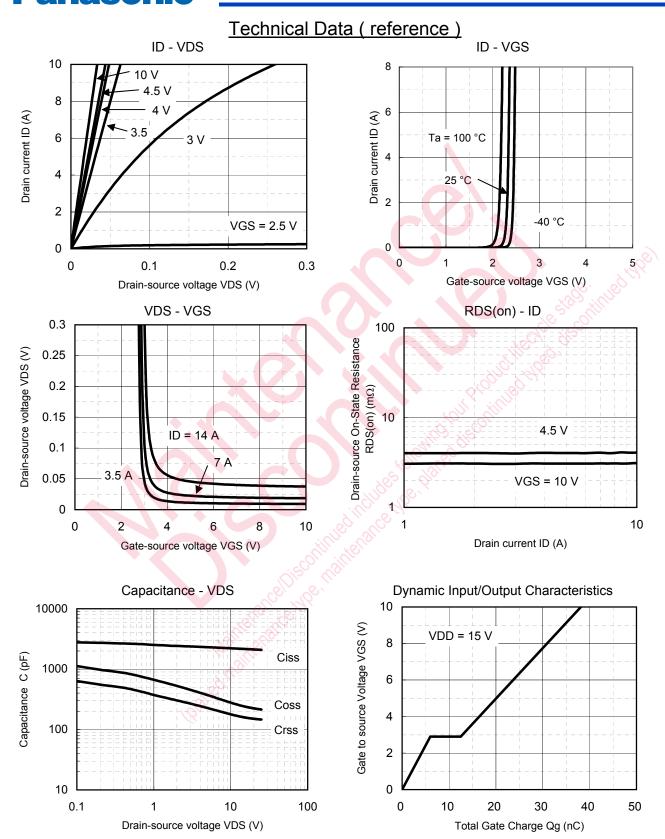
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*1 Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time



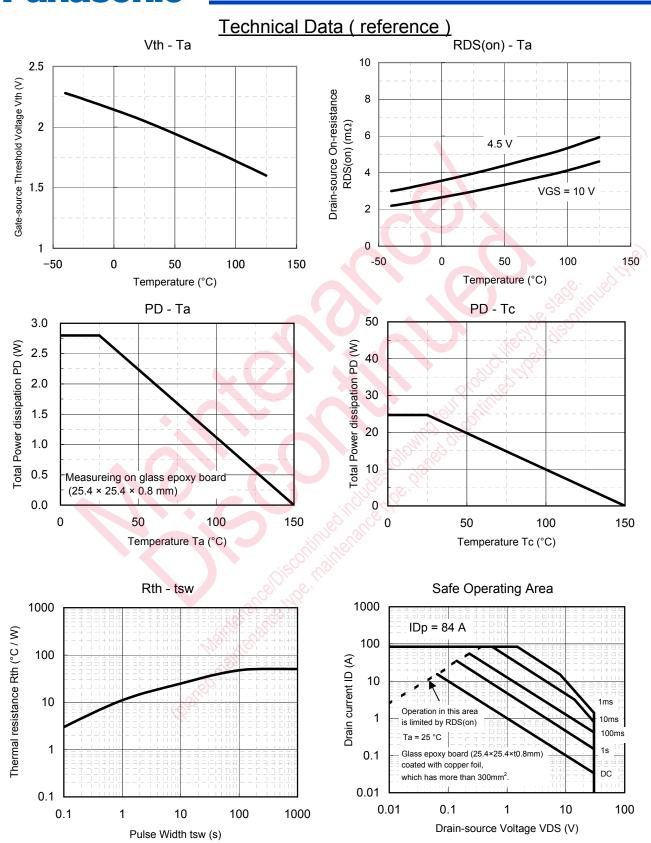
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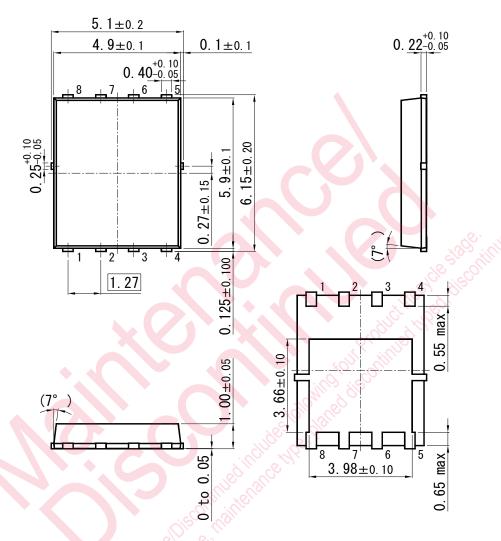
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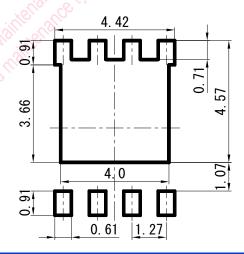
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HSO8-F4-B



■ Land Pattern (Reference) (Unit: mm)



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